

# KA5x03xx-SERIES

KA5H0365R, KA5M0365R, KA5L0365R, KA5M0365RN,  
 KA5L0365RN, KA5H0380R, KA5M0380R, KA5L0380R  
 Fairchild Power Switch(FPS)

## Features

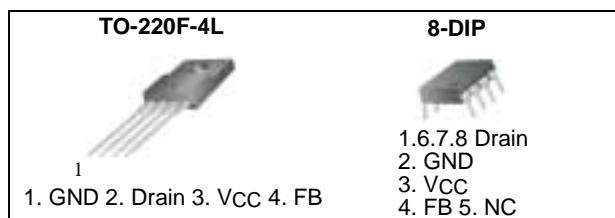
- Precision Fixed Operating Frequency (100/67/50kHz)
- Low Start-up Current(Typ. 100uA)
- Pulse by Pulse Current Limiting
- Over Load Protection
- Over Voltage Protection (Min. 25V)
- Internal Thermal Shutdown Function
- Under Voltage Lockout
- Internal High Voltage Sense FET
- Auto-Restart Mode

## Applications

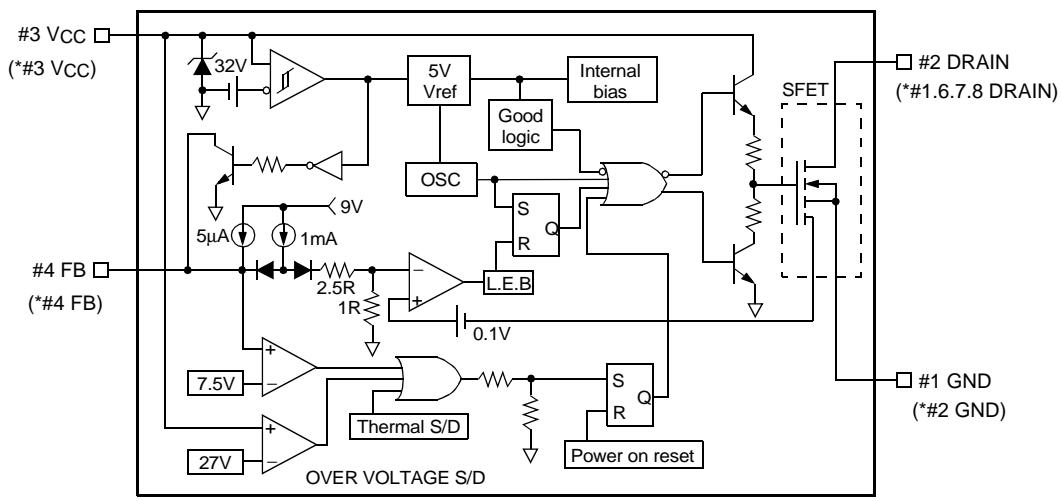
- SMPS for VCR, SVR, STB, DVD & DVCD
- SMPS for Printer, Facsimile & Scanner
- Adaptor for Camcorder

## Description

The Fairchild Power Switch(FPS) product family is specially designed for an off-line SMPS with minimal external components. The Fairchild Power Switch(FPS) consist of high voltage power SenseFET and current mode PWM IC. Included PWM controller features integrated fixed frequency oscillator, under voltage lock-out, leading edge blanking, optimized gate turn-on/turn-off driver, thermal shutdown protection, over voltage protection, and temperature compensated precision current sources for loop compensation and fault protection circuitry compared to discrete MOSFET and PWM controller or RCC solution, The Fairchild Power Switch(FPS) can reduce total component count, design size, weight and at the same time increase efficiency, productivity, and system reliability. It has a basic platform well suited for cost effective design in either a flyback converter or a forward converter.



## Internal Block Diagram



## Absolute Maximum Ratings

(Ta=25°C, unless otherwise specified)

Characteristic	Symbol	Value	Unit
<b>KA5H0365R, KA5M0365R, KA5L0365R, KA5M0365RN, KA5L0365RN</b>			
Maximum Drain Voltage	V <sub>D,MAX</sub>	650	V
Drain-Gate Voltage (RGS=1MΩ)	V <sub>DGR</sub>	650	V
Gate-Source (GND) Voltage	V <sub>GS</sub>	±30	V
Drain Current Pulsed <sup>(1)</sup>	I <sub>DM</sub>	12.0	ADC
Continuous Drain Current (T <sub>C</sub> =25°C)	I <sub>D</sub>	3.0	ADC
Continuous Drain Current (T <sub>C</sub> =100°C)	I <sub>D</sub>	2.4	ADC
Single Pulsed Avalanche Energy <sup>(2)</sup>	E <sub>AS</sub>	358	mJ
Maximum Supply Voltage	V <sub>CC,MAX</sub>	30	V
Analog Input Voltage Range	V <sub>FB</sub>	-0.3 to V <sub>SD</sub>	V
Total Power Dissipation	P <sub>D</sub>	75	W
	Darting	0.6	W/°C
Operating Junction Temperature.	T <sub>J</sub>	+160	°C
Operating Ambient Temperature.	T <sub>A</sub>	-25 to +85	°C
Storage Temperature Range.	T <sub>STG</sub>	-55 to +150	°C
<b>KA5H0380R, KA5M0380R, KA5L0380R</b>			
Maximum Drain Voltage	V <sub>D,MAX</sub>	800	V
Drain-Gate Voltage (RGS=1MΩ)	V <sub>DGR</sub>	800	V
Gate-Source (GND) Voltage	V <sub>GS</sub>	±30	V
Drain Current Pulsed <sup>(1)</sup>	I <sub>DM</sub>	12.0	ADC
Continuous Drain Current (T <sub>C</sub> =25°C)	I <sub>D</sub>	3.0	ADC
Continuous Drain Current (T <sub>C</sub> =100°C)	I <sub>D</sub>	2.1	ADC
Single Pulsed Avalanche Energy <sup>(2)</sup>	E <sub>AS</sub>	95	mJ
Maximum Supply Voltage	V <sub>CC,MAX</sub>	30	V
Analog Input Voltage Range	V <sub>FB</sub>	-0.3 to V <sub>SD</sub>	V
Total Power Dissipation	P <sub>D</sub>	75	W
	Darting	0.6	W/°C
Operating Junction Temperature.	T <sub>J</sub>	+160	°C
Operating Ambient Temperature.	T <sub>A</sub>	-25 to +85	°C
Storage Temperature Range.	T <sub>STG</sub>	-55 to +150	°C

**Note:**

1. Repetitive rating: Pulse width limited by maximum junction temperature
2. L = 51mH, starting T<sub>j</sub> = 25°C
3. L = 13μH, starting T<sub>j</sub> = 25°C

## Electrical Characteristics (SenseFET Part)

(Ta = 25°C unless otherwise specified)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
<b>KA5H0365R, KA5M0365R, KA5L0365R- EXCEPT KA5M0365RN, KA5L0365RN</b>						
Drain-Source Breakdown Voltage	BVDSS	VGS=0V, ID=50µA	650	-	-	V
Zero Gate Voltage Drain Current	IDSS	VDS=Max. Rating, VGS=0V	-	-	50	µA
		VDS=0.8Max. Rating, VGS=0V, TC=125°C	-	-	200	µA
Static Drain-Source on Resistance <sup>(Note)</sup>	RDS(ON)	VGS=10V, ID=0.5A	-	3.6	4.5	Ω
Forward Transconductance <sup>(Note)</sup>	gfs	VDS=50V, ID=0.5A	2.0	-	-	S
Input Capacitance	Ciss	VGS=0V, VDS=25V, f=1MHz	-	720	-	pF
Output Capacitance	Coss		-	40	-	
Reverse Transfer Capacitance	Crss		-	40	-	
Turn on Delay Time	td(on)	VDD=0.5B VDSS, ID=1.0A (MOSFET switching time is essentially independent of operating temperature)	-	150	-	nS
Rise Time	tr		-	100	-	
Turn Off Delay Time	td(off)		-	150	-	
Fall Time	tf		-	42	-	
Total Gate Charge (Gate-Source+Gate-Drain)	Qg	VGS=10V, ID=1.0A, VDS=0.5B VDSS (MOSFET switching time is essentially independent of operating temperature)	-	-	34	nC
Gate-Source Charge	Qgs	-	7.3	-		
Gate-Drain (Miller) Charge	Qgd	-	13.3	-		
<b>KA5H0380R, KA5M0380R, KA5L0380R</b>						
Drain-Source Breakdown Voltage	BVDSS	VGS=0V, ID=50µA	800	-	-	V
Zero Gate Voltage Drain Current	IDSS	VDS=Max. Rating, VGS=0V	-	-	250	µA
		VDS=0.8Max. Rating, VGS=0V, TC=125°C	-	-	1000	µA
Static Drain-Source on Resistance <sup>(Note)</sup>	RDS(ON)	VGS=10V, ID=0.5A	-	4.0	5.0	Ω
Forward Transconductance <sup>(Note)</sup>	gfs	VDS=50V, ID=0.5A	1.5	2.5	-	S
Input Capacitance	Ciss	VGS=0V, VDS=25V, f=1MHz	-	779	-	pF
Output Capacitance	Coss		-	75.6	-	
Reverse Transfer Capacitance	Crss		-	24.9	-	
Turn on Delay Time	td(on)	VDD=0.5B VDSS, ID=1.0A (MOSFET switching time is essentially independent of operating temperature)	-	40	-	nS
Rise Time	tr		-	95	-	
Turn Off Delay Time	td(off)		-	150	-	
Fall Time	tf		-	60	-	
Total Gate Charge (Gate-Source+Gate-Drain)	Qg	VGS=10V, ID=1.0A, VDS=0.5B VDSS (MOSFET switching time is essentially independent of operating temperature)	-	-	34	nC
Gate-Source Charge	Qgs	-	7.2	-		
Gate-Drain (Miller) Charge	Qgd	-	12.1	-		

**Note:**

1. Pulse test: Pulse width ≤ 300µS, duty ≤ 2%

$$2. S = \frac{1}{R}$$

**Electrical Characteristics (Control Part) (Continued)**

(Ta = 25°C unless otherwise specified)

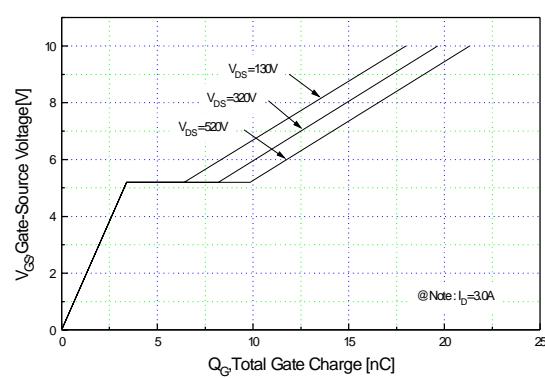
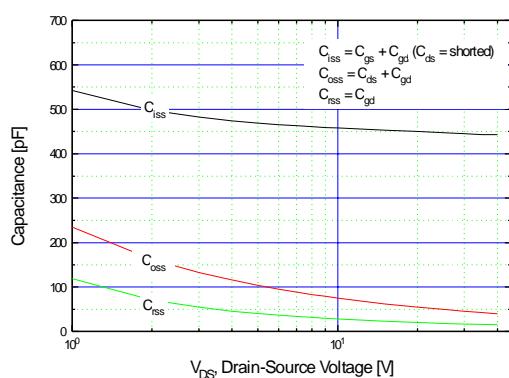
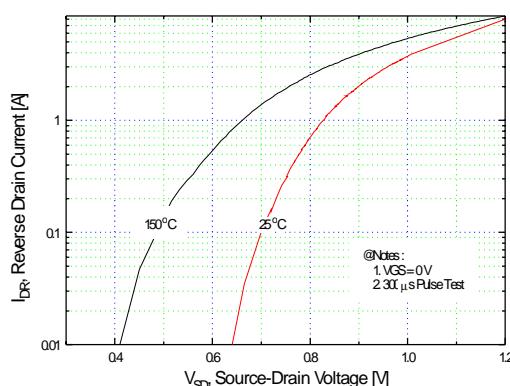
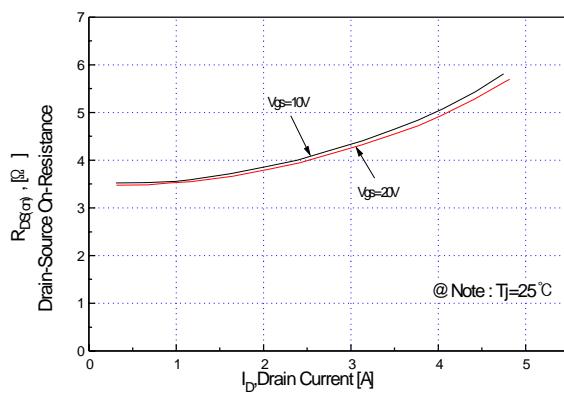
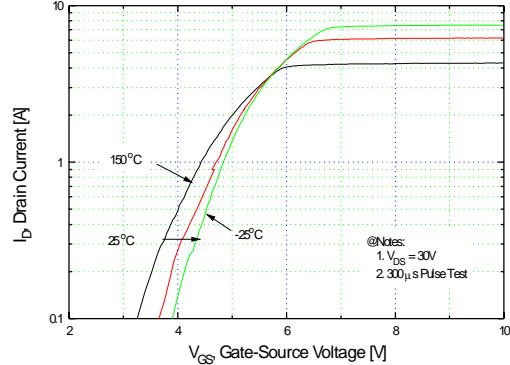
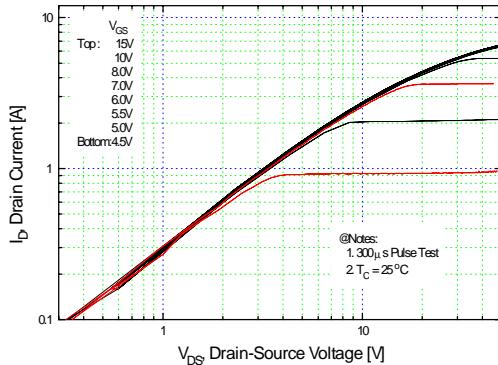
Characteristic	Symbol	Test condition	Min.	Typ.	Max.	Unit
<b>UVLO SECTION</b>						
Start Threshold Voltage	V <sub>START</sub>	V <sub>FB</sub> =GND	14	15	16	V
Stop Threshold Voltage	V <sub>STOP</sub>	V <sub>FB</sub> =GND	8.2	8.8	9.4	V
<b>OSCILLATOR SECTION</b>						
Initial Accuracy	F <sub>OSC</sub>	<b>KA5H0365R KA5H0380R</b>	90	100	110	kHz
Initial Accuracy	F <sub>OSC</sub>	<b>KA5M0365R KA5M0365RN KA5M0380R</b>	61	67	73	kHz
Initial Accuracy	F <sub>OSC</sub>	<b>KA5L0365R KA5L0365RN KA5L0380R</b>	45	50	55	kHz
Frequency Change With Temperature <sup>(2)</sup>	-	-25°C ≤ Ta ≤ +85°C	-	±5	±10	%
Maximum Duty Cycle	D <sub>max</sub>	<b>KA5H0365R KA5H0380R</b>	62	67	72	%
Maximum Duty Cycle	D <sub>max</sub>	<b>KA5M0365R KA5M0365RN KA5M0380R KA5L0365R KA5L0365RN KA5L0380R</b>	72	77	82	%
<b>FEEDBACK SECTION</b>						
Feedback Source Current	I <sub>FB</sub>	Ta=25°C, 0V ≤ V <sub>fb</sub> ≤ 3V	0.7	0.9	1.1	mA
Shutdown Feedback Voltage	V <sub>SD</sub>	V <sub>fb</sub> ≥ 6.5V	6.9	7.5	8.1	V
Shutdown Delay Current	I <sub>delay</sub>	Ta=25°C, 5V ≤ V <sub>fb</sub> ≤ V <sub>SD</sub>	4	5	6	μA
<b>REFERENCE SECTION</b>						
Output Voltage <sup>(1)</sup>	V <sub>ref</sub>	Ta=25°C	4.80	5.00	5.20	V
Temperature Stability <sup>(1)(2)</sup>	V <sub>ref/ΔT</sub>	-25°C ≤ Ta ≤ +85°C	-	0.3	0.6	mV/°C
<b>CURRENT LIMIT(SELF-PROTECTION)SECTION</b>						
Peak Current Limit	I <sub>OVER</sub>	Max. inductor current	1.89	2.15	2.41	A
<b>PROTECTION SECTION</b>						
Over Voltage Protection	V <sub>OVP</sub>	V <sub>CC</sub> ≥24V	25	27	29	V
Thermal Shutdown Temperature <sup>(1)</sup>	T <sub>SD</sub>	-	140	160	-	°C
<b>TOTAL STANDBY CURRENT SECTION</b>						
Start-up Current	I <sub>START</sub>	V <sub>CC</sub> =14V	-	100	170	μA
Operating Supply Current (Control Part Only)	I <sub>OP</sub>	V <sub>CC</sub> ≤ 28	-	7	12	mA

**Note:**

1. These parameters, although guaranteed, are not 100% tested in production
2. These parameters, although guaranteed, are tested in EDS(water test) process

## Typical Performance Characteristics(SenseFET part)

(EXCEPT KA5M0365RN, KA5L0365RN)



## Typical Performance Characteristics (Continued)

(EXCEPT KA5M0365RN, KA5L0365RN)

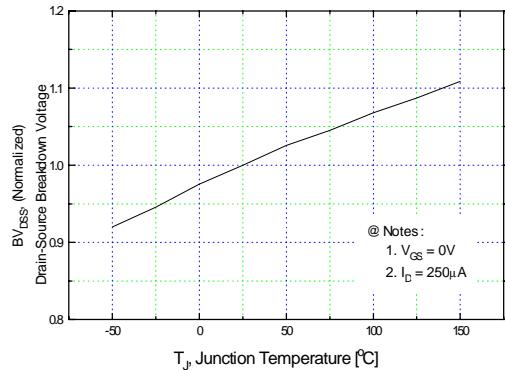


Figure 7. Breakdown Voltage vs. Temperature

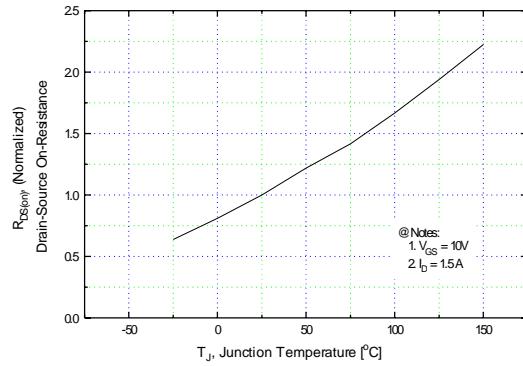


Figure 8. On-Resistance vs. Temperature

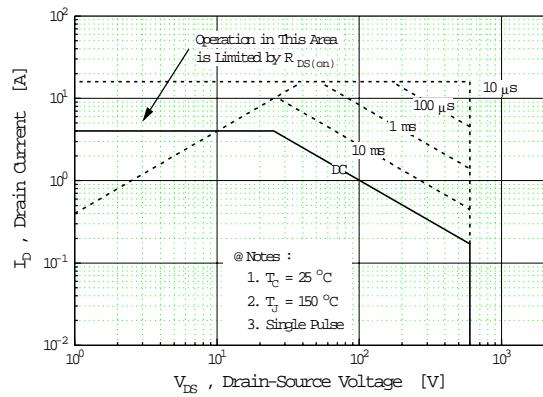


Figure 9. Max. Safe Operating Area

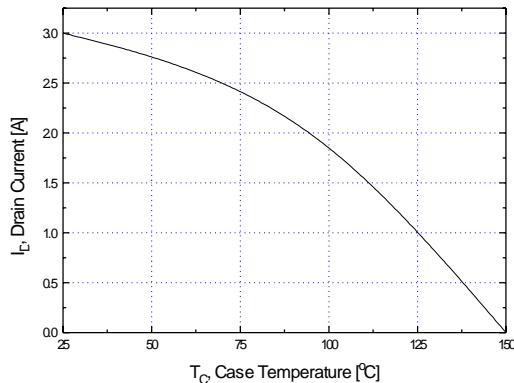


Figure 10. Max. Drain Current vs. Case Temperature

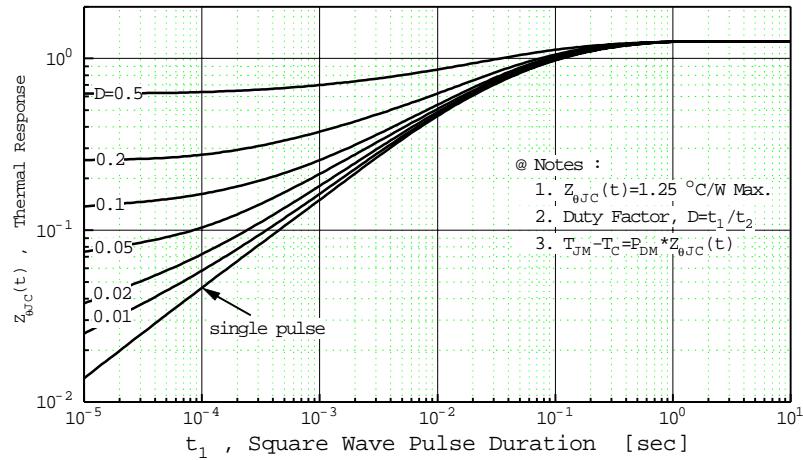
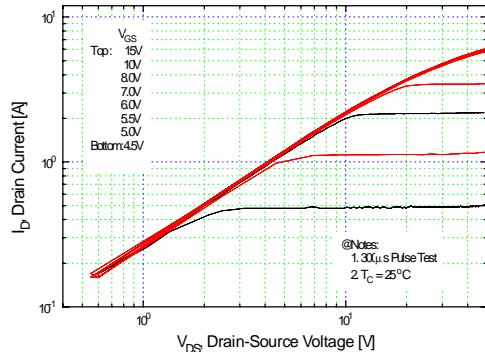


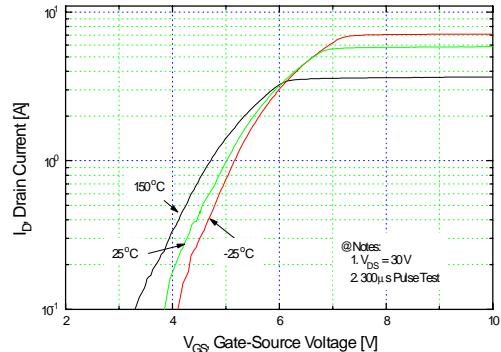
Figure 11. Thermal Response

## Typical Performance Characteristics (Continued)

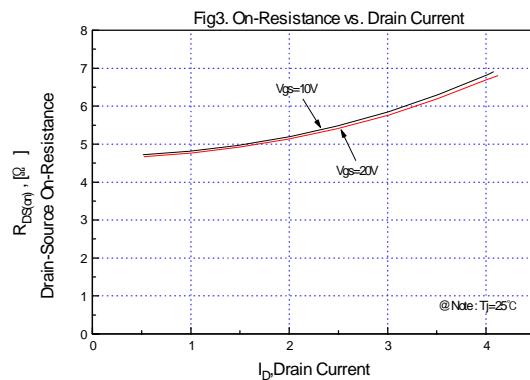
(KA5H0380R, KA5M0380R, KA5L0380R)



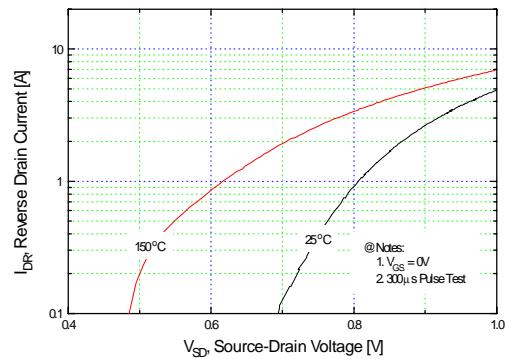
**Figure 1. Output Characteristics**



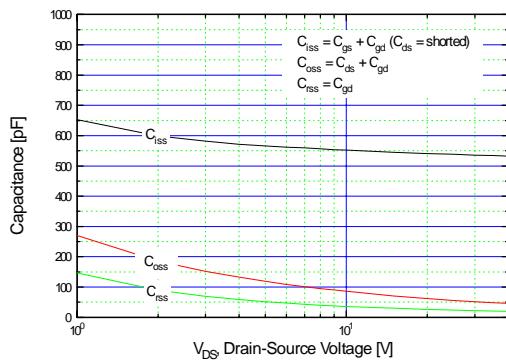
**Figure 2. Transfer Characteristics**



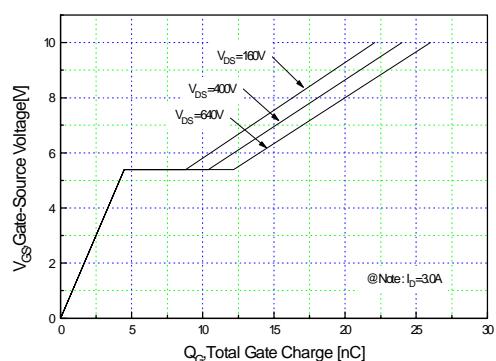
**Figure 3. On-Resistance vs. Drain Current**



**Figure 4. Source-Drain Diode Forward Voltage**



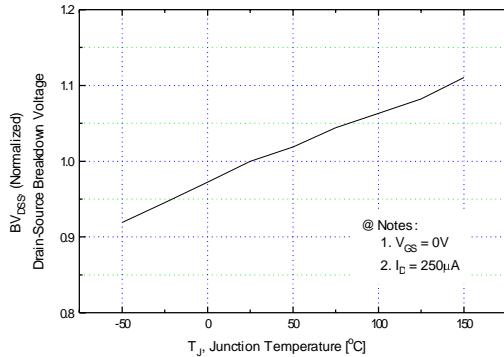
**Figure 5. Capacitance vs. Drain-Source Voltage**



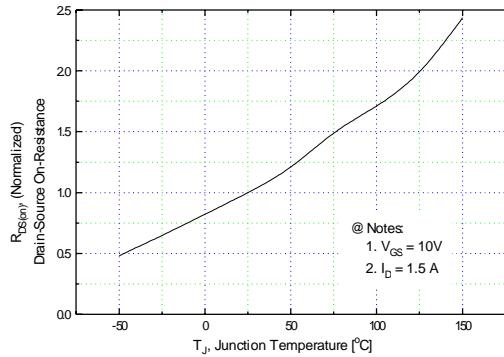
**Figure 6. Gate Charge vs. Gate-Source Voltage**

## Typical Performance Characteristics (Continued)

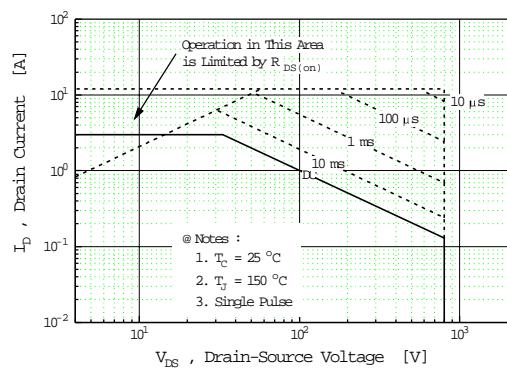
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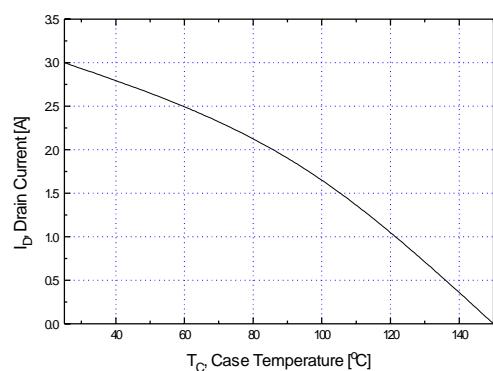
**Figure 7. Breakdown Voltage vs. Temperature**



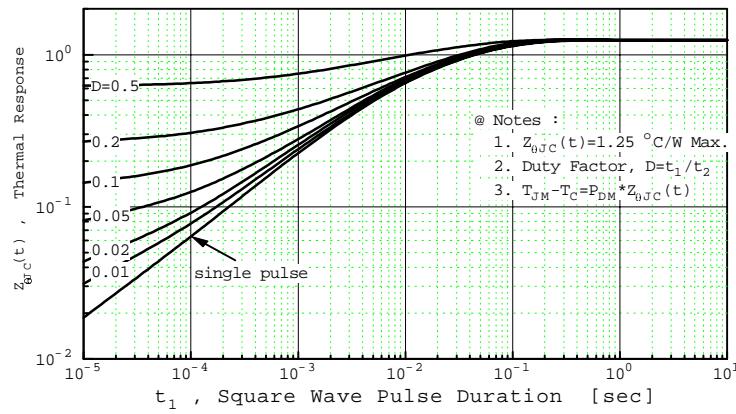
**Figure 8. On-Resistance vs. Temperature**



**Figure 9. Max. Safe Operating Area**



**Figure 10. Max. Drain Current vs. Case Temperature**



**Figure 11. Thermal Response**

## Typical Performance Characteristics (Control Part) (Continued)

(These characteristic graphs are normalized at  $T_a = 25^\circ\text{C}$ )

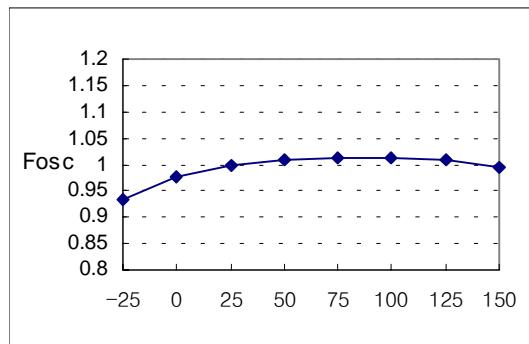


Figure 1. Operating Frequency

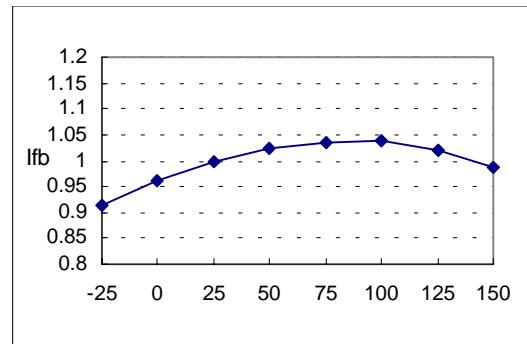


Figure 2. Feedback Source Current

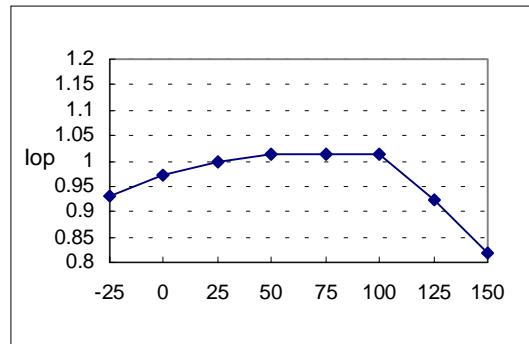


Figure 3. Operating Supply Current

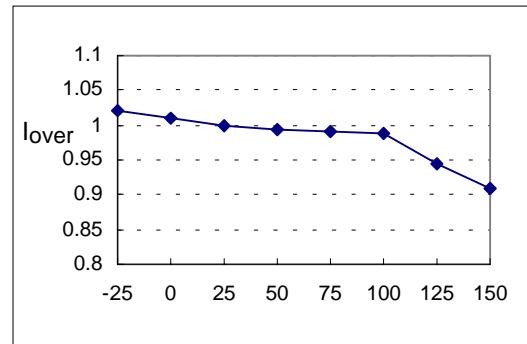


Figure 4. Peak Current Limit

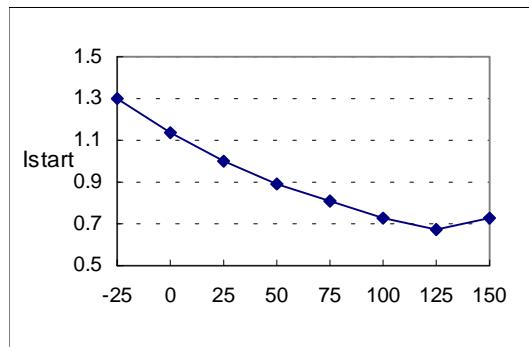


Figure 5. Start up Current

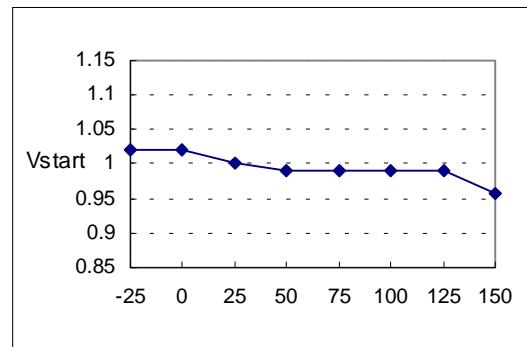


Figure 6. Start Threshold Voltage

## Typical Performance Characteristics (Continued)

(These characteristic graphs are normalized at  $T_a = 25^\circ\text{C}$ )

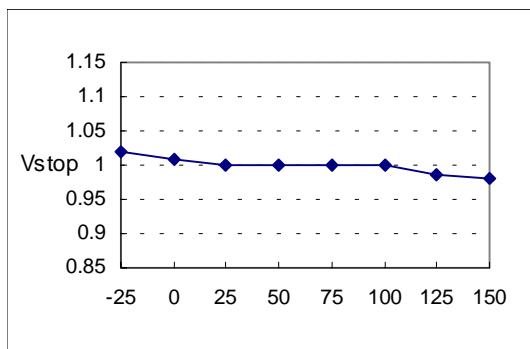


Figure 7. Stop Threshold Voltage

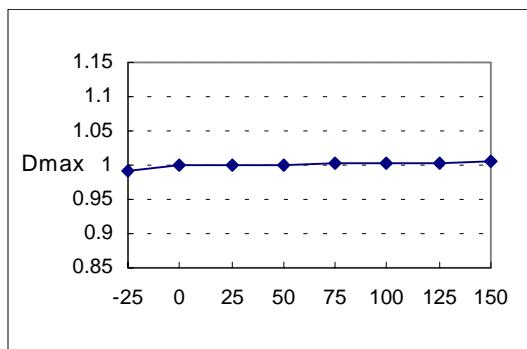


Figure 8. Maximum Duty Cycle

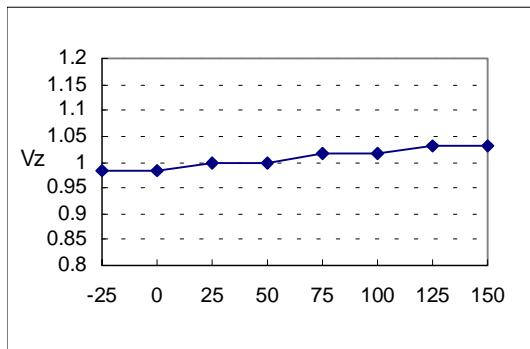


Figure 9. VCC Zener Voltage

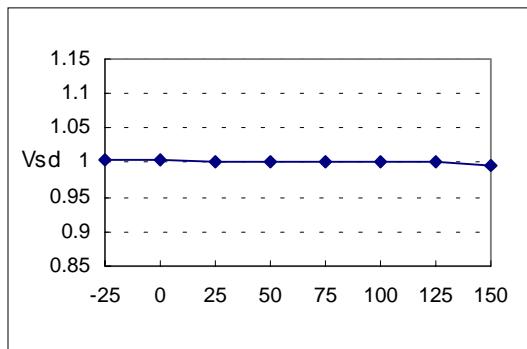


Figure 10. Shutdown Feedback Voltage

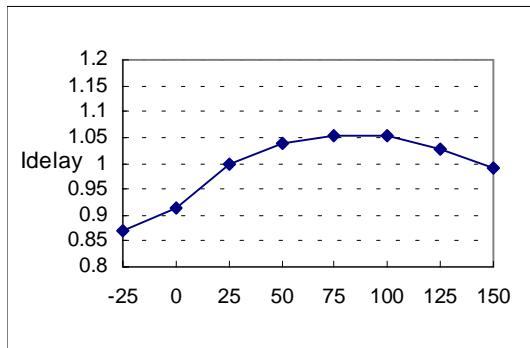


Figure 11. Shutdown Delay Current

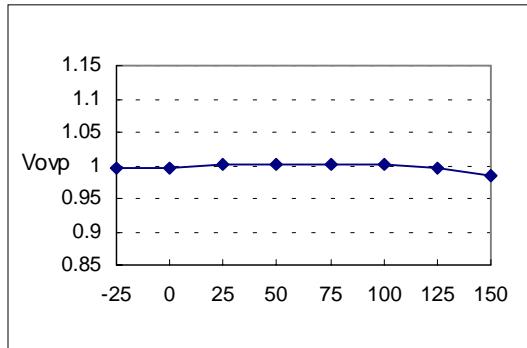


Figure 12. Over Voltage Protection

## Typical Performance Characteristics (Continued)

(These characteristic graphs are normalized at  $T_a = 25^\circ\text{C}$ )

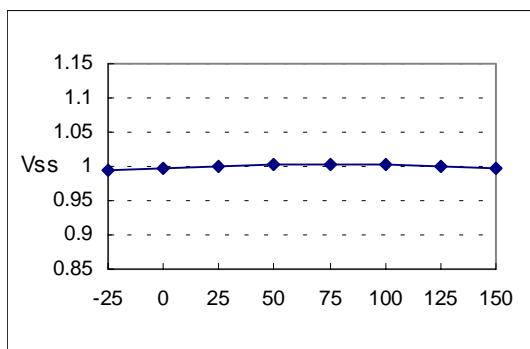


Figure13. Soft Start Voltage

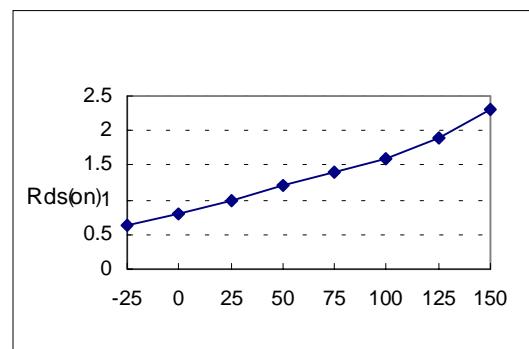
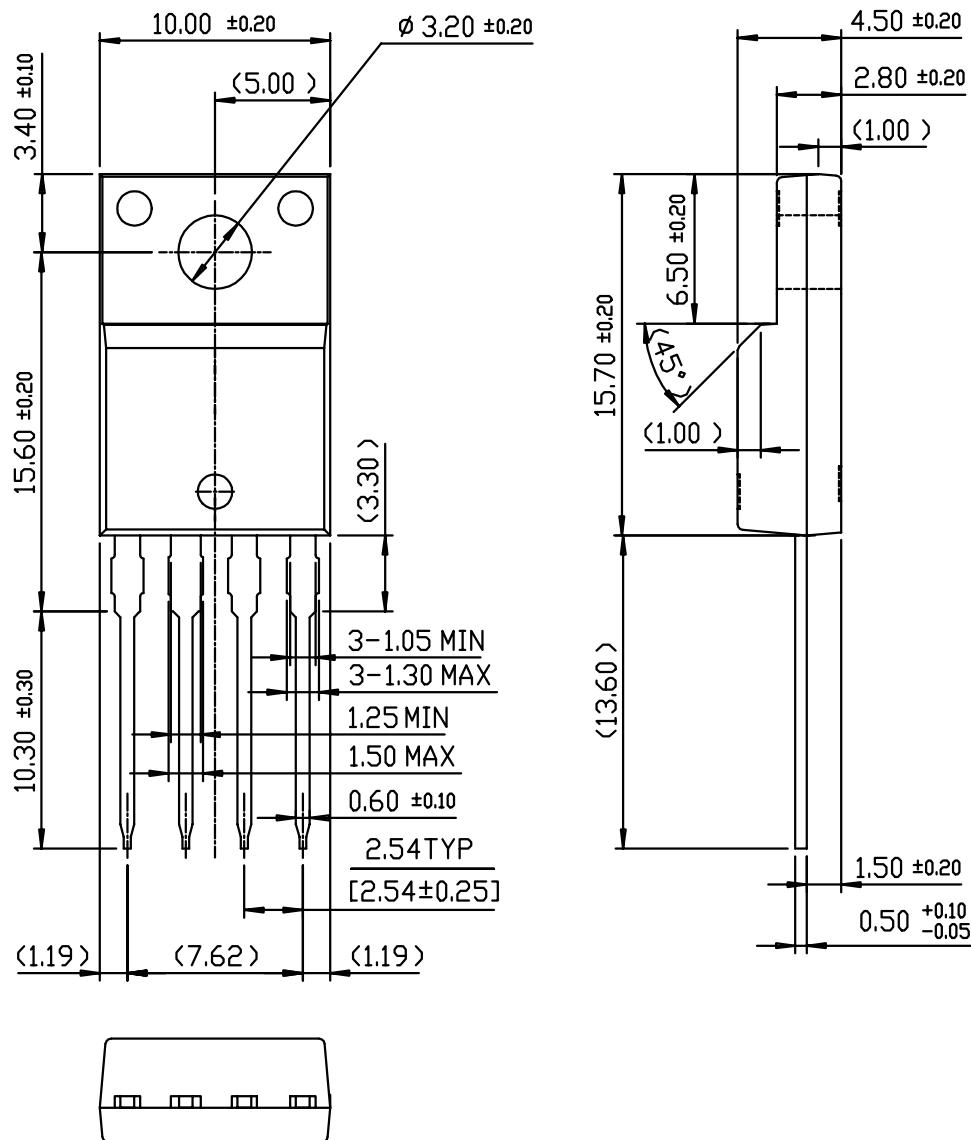


Figure 14. Static Drain-Source on Resistance

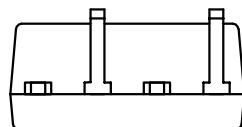
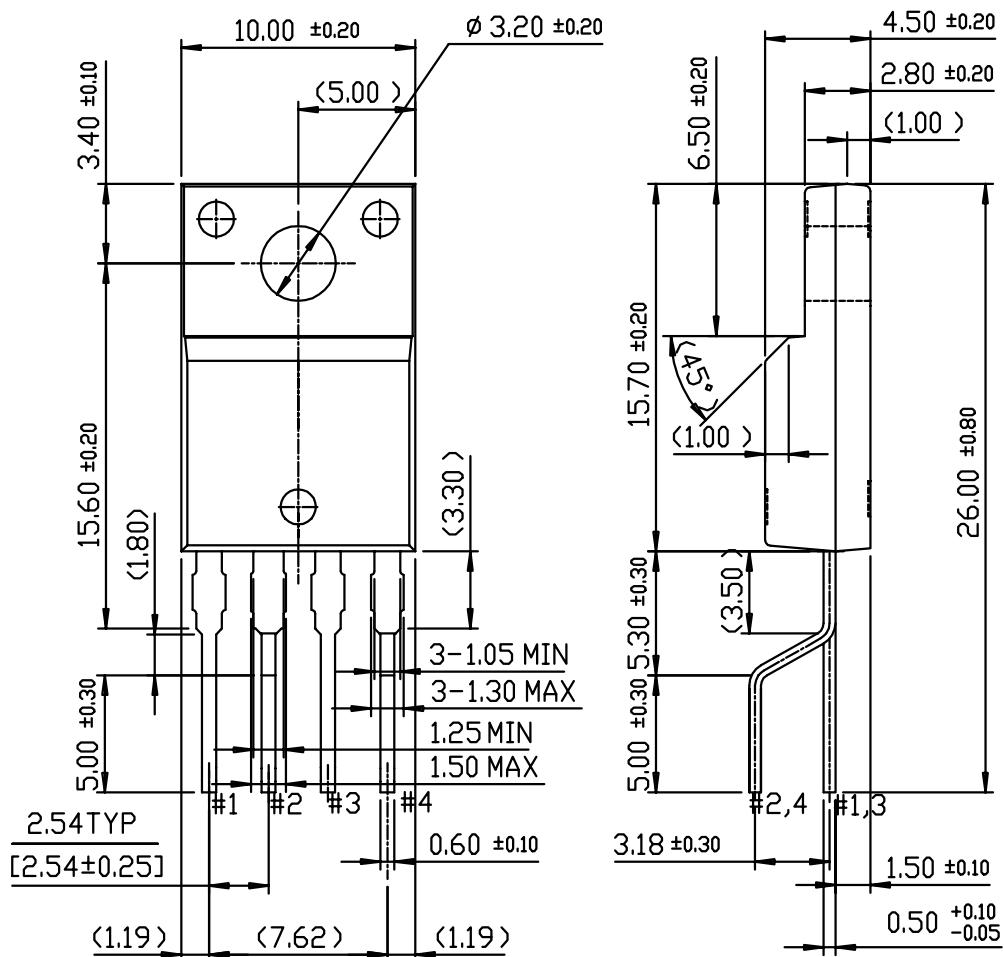
## Package Dimensions

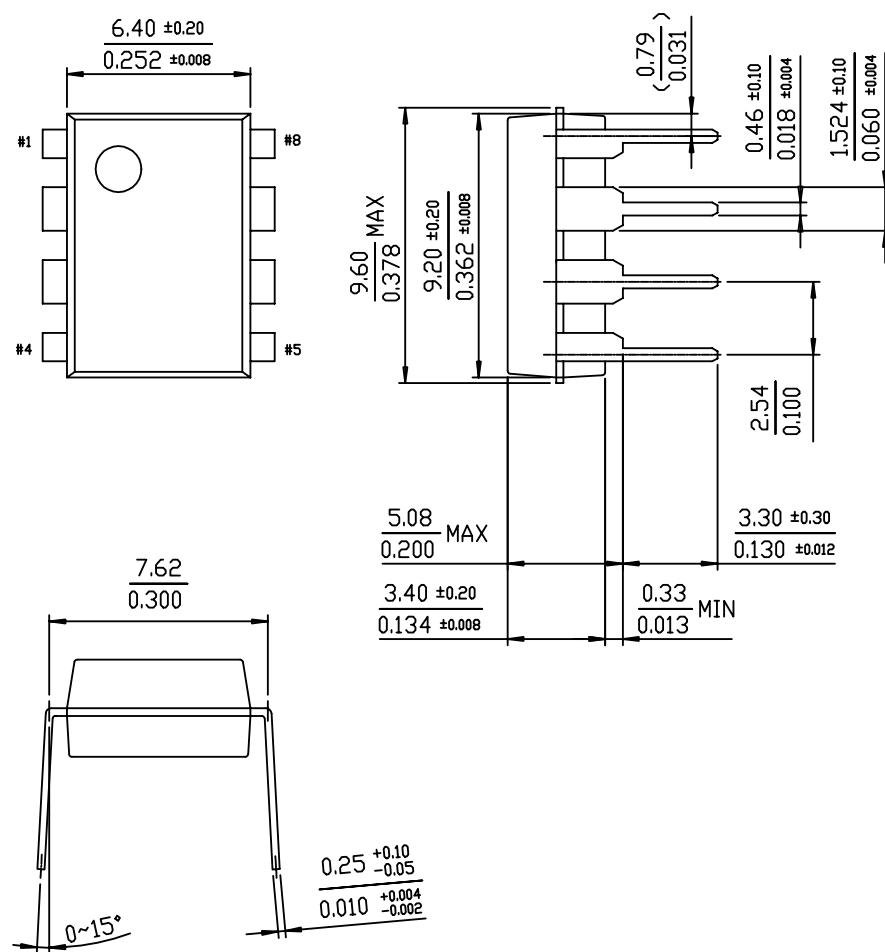
**TO-220F-4L**



## Package Dimensions (Continued)

### TO-220F-4L(Forming)



**Package Dimensions** (Continued)**8-DIP**

## Ordering Information

<b>Product Number</b>	<b>Package</b>	<b>Marking Code</b>	<b>BVDSS</b>	<b>Fosc</b>	<b>RDS(on)</b>
KA5H0365RTU	TO-220F-4L	5H0365R	650V	100kHz	3.6Ω
KA5H0365RYDTU	TO-220F-4L(Forming)				
KA5M0365RTU	TO-220F-4L	5M0365R	650V	67kHz	3.6Ω
KA5M0365RYDTU	TO-220F-4L(Forming)				
KA5L0365RTU	TO-220F-4L	5L0365R	650V	50kHz	3.6Ω
KA5L0365RYDTU	TO-220F-4L(Forming)				
KA5M0365RN	8-DIP	5M0365RN	650V	67kHz	3.6Ω
KA5L0365RN	8-DIP	5L0365RN	650V	50kHz	3.6Ω
<b>Product Number</b>	<b>Package</b>	<b>Marking Code</b>	<b>BVDSS</b>	<b>Fosc</b>	<b>RDS(on)</b>
KA5H0380RTU	TO-220F-4L	5H0380R	800V	100kHz	4.6Ω
KA5H0380RYDTU	TO-220F-4L(Forming)				
KA5M0380RTU	TO-220F-4L	5M0380R	800V	67kHz	4.6Ω
KA5M0380RYDTU	TO-220F-4L(Forming)				
KA5L0380RTU	TO-220F-4L	5L0380R	800V	50kHz	4.6Ω
KA5L0380RYDTU	TO-220F-4L(Forming)				

TU :Non Forming Type

YDTU : Forming type

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.